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Surface-enhanced Raman scattering from semiconductor and graphene quantum dots coupled to metallic-film-onnanosphere substrates

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Abstract. In this article, we perform surface-enhanced Raman scattering (SERS) with a periodically corrugated metallic substrate obtained by evaporating an Ag film onto an artificial opal crystal, which is a self-assembled lattice of SiO_2 600-nm spheres. These metallic-film-on-nanosphere (MFON) surfaces are characterized by scanning electron microscopy for different Ag film thicknesses ranging from 44 to 620 nm. Raman scattering spectra are measured for two different types of quantum dots, CdTeSe quantum dots (QDs) and graphene quantum dots (GQDs). We are able to show that enhancement of the Raman spectra can be obtained for all MFON substrates and for both types of QDs. For both CdTeSe and graphene quantum dots, the strongest SERS effect was observed in samples with 135 nm Ag thickness. This is attributed to the formation of hot spots in the nanogap dips of the Ag film.

Keywords: SiO₂ spheres, opal, Ag plasmonic films, CdTeSe quantum dots, graphene quantum dots GQDs, Raman spectra, SERS.

1. Introduction

Colloidal quantum dots (QDs) have been the subject of a vast range of fundamental and applied studies. Various compositions were considered in order to tune their emission wavelength, including ternary alloyed QDs such as CdTeSe whose emission is in the red to near-infrared region [1-7], with applications in biosensing, displays, and potential future developments in solar cells, lighting, opto-electronics or quantum optics. More recently, graphene quantum dots (GQDs) have been synthetized. They are small graphene fragments (less than 20 nm in size), in which electron transport is confined in all three dimensions. GQDs combine the unique photoelectronic properties attributed to quantum confinement effects [8, 9] and edge effects [10-12]. They are considered for applications in solar energy, photocatalysts, biosensors, bioimaging, drug delivery, photovoltaic and biomedical devices thanks to their bright and stable emission and good biological compatibility [13-19].

Photoluminescence is most generally used to detect QDs due to its great sensitivity. Luminescence from small amounts of QDs can easily be detected, even down to the singleemitter level when the quantum yield is sufficient. Raman spectroscopy provides less sensitivity because of its much smaller cross-section, but it offers a wealth of information about the QD's vibrational properties which is not accessible by other methods. The frequency of a phonon's Raman peak can be related to the QD's size and shape as well as to its internal strain or to its chemical composition or surface state. Raman spectroscopy can thus be used to analyze QDs and guide their synthesis, to study the vibrational properties in connection with relaxation mechanisms, or for multiplexed detection of biomarkers of different compositions. For instance, for alloyed QDs, the Raman spectra can be related to the concentration of the various components of the alloy [1]. For GQDs, Raman spectroscopy can be used to demonstrate the formation of the quantum dots.

When Raman intensity is too low to be detected, surface-enhanced Raman spectroscopy (SERS) can be used: the nanoparticles are deposited on a metallic film such as Au, Ag or Al: these films present surface plasmon modes at the air-metal interface with strongly confined electromagnetic fields which can favor light emission and absorption. SERS can be used for chemical analysis, detection of pollutants or bacterias, photochemical studies or vibrational spectroscopy [20] down to the single-emitter level [21, 22]. The search for efficient and unexpensive SERS metallic substrates is a very active field and many different substrates and fabrication methods have been proposed, as exemplified most recently by Au nanoparticles obtained by femtosecond exposure of a Au film [23], by bipyramid Au nanoparticles [24], by Ag-nanoparticles growth on Si by replacement method [25] or by stripes of vertical or horizontal Au nanorods [26]. The key element is the presence of sharp tips or dips on the surface of the metallic substrate, where plasmonic modes can be strongly confined and create "hot spots". Hot spots are also essential to future applications of plasmonics in photochemistry or photovoltaics [20]. A few papers have applied SERS to QDs of different materials : CdS [27], CdSe [28-30], PbS [31], SnO₂ [32] or Si [33]. SERS is a promising technique for QD detection and may be applied for the detection of traces of nanoparticles, for the detection of biomarkers or for in-situ tracking of the nanoparticles' surface chemical properties such as their oxidation [31, 33]. SERS has also allowed phonon modes analysis of single CdSe nanoplatelets [34].

Deposition of "metallic film on nanosphere" (MFON) samples has emerged as a convenient and reproducible way to produce a corrugated metallic surface for SERS analysis [35, 36]. These samples are obtained by evaporating a metallic layer on top of an ordered self-organized array of polymer or silica nanospheres. SERS enhancement factors in the range from 10³ to 10¹¹ have been reported [20]. Promising SERS measurements have been performed with dye molecules on MFON substrates [37-39] as reviewed in [20] and applications have been demonstrated for DNA detection [40], ricine [41] or anthrax [42] sensing, or tracking of alumina atomic layer deposition [43]. However, to our knowledge, no SERS study on QDs have used MFON substrates - although a few groups have considered QD photoluminescence enhancement by MFON [44, 45].

In this paper, we use MFON substrates for SERS characterization of different types of QDs. We start the paper with a precise structural characterization of the sample fabrication steps: silica spheres synthesis, self-assembled deposition of the spheres into a three-dimension lattice (opal), and Ag layer deposition with various thicknesses considered. We then analyze the SERS spectra on the different substrates for two types of quantum dots: CdTeSe QDs and GQDs. We show that SERS can be obtained with both types of QDs for all substrates, discuss the measured SERS enhancement factor and identify the best Ag thickness.

2. Experimental

2.1. Preparation of SiO₂ spheres and fabrication of opal films on glass substrate

We have synthesized SiO_2 spheres in absolute ethanol solvent based on W. Stoeber's method [46]. However, we have made improvements to the fabrication method and used high-grade purity 1,4-dioxane as organic solvents to obtain large 600 nm SiO_2 spheres with narrow size distribution, as suggested in [47]. Tetraethyl orthosilicate (TEOS) 98% purchased from Sigma–Aldrich has been used as the silica precursor. Absolute ethanol and 1,4-dioxane 99.8% have been used as a solvent. The desired pH of approximately 10 was controlled by adding dilute ammonia to distilled water.

The typical synthesis process that we used is as follows: 20 ml of tetraethyl orthosilicate (TEOS) was dissolved in a mixture of 160 ml absolute ethanol and 40ml 1,4-dioxane with magnetic stirring at room temperature. After a 20-minute equilibration, a dilute solution of 15 ml 25% NH₄OH in 50 ml H₂O was added to the solution so that pH = 10. After 5 minutes, the solution turned white revealing the formation of SiO₂ nanospheres, then became opaque white.

This reaction lasted 24 hours and the SiO₂ spheres increased up to a size close to 350 nm. After one day, the size of the SiO₂ nanospheres was controlled by adding 10 ml TEOS after each 2hour period and observing SEM images during the spheres' growth process. For 600 nm spheres, six steps of TEOS addition (or a total amount of 80 ml TEOS) were necessary for a complete growth process. When SiO₂ spheres reached the average size of 600 nm, an amount of 200 ml absolute ethanol was added, then stirred again for 8h to obtain stable sol. Finally, the resulting white sol was diluted again in 300 ml ethanol and stored in a polyethylene bottle for sedimentation of SiO₂ spheres.

The white sedimentation was washed with absolute ethanol by centrifuging at 1200 rpm for 3 minutes to obtain SiO_2 spheres. The washing process was repeated five times in order to remove the impurities completely. The obtained opaque white SiO_2 spheres with an average size of 600 nm were dispersed again in absolute ethanol or dried for the next experiments.

A three-dimension dielectric lattice can be obtained by self- organization of the silica spheres, leading to artificial opal samples. The preparation of opal films has been carried out as described in our previous paper [48]: a silica glass substrate was placed in a transparent cup at a 30 degree angle to the cup wall. This cup contained the suspensions of suitable SiO₂ concentrations (up to 10 wt %) in absolute ethanol. In order to obtain a high-quality regular assembly of the SiO₂ spheres by self-organization at the meniscus, the ethanol was evaporated very slowly at 30° C. The colloidal opal crystals then dried naturally at room temperature.

2.2. Deposition of the Ag film on the opal ordered template

Silver and gold are the most prominent metals for plasmonic samples in the visible range. Gold provides a better stability but its ohmic losses are higher, especially in the blue-green range which is considered in the present SERS measurements. For this reason, we used silver for the design of our MFON samples.

Ag films were obtained by evaporating a Ag layer on a self-assembled opal, with a different Ag thickness for each sample. The Ag layers were deposited onto the opal by thermal evaporation using a VHD-30 system. The deposition process was carried out at a pressure of 10⁻⁵ torr. The substrates were kept at room temperature and the distance from the evaporation source to the substrates was 20 cm. The thickness of the Ag layer was monitored and controlled using a quartz oscillator system. Ag layers were evaporated with various thicknesses.

A structural characterization of the MFON substrates was carried out by field emission scanning electron microscopy (FE-SEM) (S4800-Hitachi) to determine the size of the SiO₂ spheres, the morphology of the opal samples and check the Ag layer thickness. The Ag layer thickness was estimated from the SEM images as the height at the top of the spheres subtracted by the spheres diameter. The obtained Ag thicknesses ranged from 44 to 620 nm.

2.3. SERS measurements

The CdTeSe QDs samples used in this study, of diameter 6.3 nm, were fabricated by the method published in [1], and the GQDs samples by the one published in [49, 50]. The CdTeSe QDs have an emission at 735 nm and an absorption at ~700 nm. The GQDs are disks of diameter 25 \pm 10 nm with an absorption peak at 350 nm and an emission peak at 470 nm.

A 12- μ L droplet of the QD solution (either CdTeSe QD or GQD) was deposited onto each MFON substrate, forming for all samples a disk of around 4-mm diameter. The Raman spectra were analyzed by Micro Raman spectroscopy (XploRA- Horiba) using the 532 nm (25 mW) excitation line from a diode-pumped, solid state laser to analyze the vibration bonds and their Raman frequencies. The laser power was 0.25 mW. A x10 objective was used to focus the excitation laser light onto the investigated samples. The size of the excitation laser spot on the sample was 1 μ m. The spectral resolution was 2 cm⁻¹. The acquisition time was 10 s. The system uses a Charge Coupled Device (CCD) receiver with with four gratings 600, 1200, 1800 and

2400 gr./mm, measuring from 100 to 4000 cm⁻¹. In this work, we have used a 1200 gr./mm grating. The Raman spectra were compared with the reference Raman spectra measured on a glass substrate with a QD droplet deposited under the same conditions.

3. Results and discussion

3.1. SiO₂ spheres and opal samples preparation

SEM images recorded at each growth stage of the SiO₂ spheres have allowed us to determine the size and growth kinetics of the SiO₂ spheres. The number of fabricated spheres will depend on the number of initial seeds created when starting the reaction. These seeds are controlled by the concentration of the source precursor that created the SiO₂, which is the amount of TEOS brought into the initial reaction compared to absolute ethanol, and the speed at which the reacting solution is stirred. When stirring the solution, the chemical reactions will happen until the initial TEOS is depleted. At this moment, we add the same amount of TEOS to the solution, to supply Si creating Si-O links with those on the surface of SiO₂ spheres. These spheres keep developing in this growth process and every time TEOS is depleted, we add another amount into the mixture, until the desired sphere size is reached, up to 600 nm. For spheres sized 600 nm, we used 1,4-dioxane as the solvent for the growth process. Figure 1 shows the SEM images of the 600-nm SiO₂ spheres (left) and the surface image of the opal sample (right). A good ordering of the silica spheres in the opal is obtained, as will be confirmed by more surface and lateral SEM images in the next figures.



Figure 1. SEM images of synthesized SiO₂ spheres with the size 600 nm (left), and of the surface of an opal sample (right).

3.2. Structural and optical properties of the MFON substrates

The MFON samples have been studied by SEM. Figure 2 a shows SEM images of a first Agcovered opal sample, with Ag-film thickness of only 5 nm. We can see that the Ag deposition forms small islands on top of the silica spheres. The amount of Ag is not sufficient to coalesce and produce a uniform film. However, for the sample in which 44 nm Ag is evaporated, the percolation threshold is reached and the evaporated Ag covers the opal surface. For instance, fig. 2b shows the surface topography of the 135 nm sample, for which the continuous deposition of the Ag layer appears clearly.



Figure 2. SEM images of opal samples coated with a 5 nm (a) and a 135-nm (b) thick Ag layer.

Figure 3 shows cross-section SEM images of the different obtained MFON samples for Ag thickness of 44 nm and above. These SEM images show that the Ag film completely covers the upper half of the silica spheres and creates a continuous corrugated metallic surface.



Figure 3. SEM images of Ag-coated opal samples with different thickness: 44, 110, 135, 200, and 620 nm.

We can measure on the SEM images the corrugation depth, which we define as the height difference between the upper and lower points of an Ag film surface profile [36]. Table 1 reports the value of the corrugation depth for each sample of different Ag thickness. For the lowest Ag thickness (44 nm), the corrugation depth is highest at 220 nm : in this case the Ag film profile follows approximately the profile of the silica spheres, which has a 300-nm depth (as the spheres have 600-nm diameter).On the other hand, for the highest Ag thickness, the MFON surface is mostly smoothed as the deposited Ag fills the space between the spheres, and the corrugation on an opal [36]. However, here the evolution of the corrugation depth as a function of the deposited Ag thickness is not monotonous as there is a competition between Ag deposition into the gaps between the spheres and deposition on the top of the spheres, the latter

being often favored due to shadowing effects. Further smoothing might be obtained by addition of a silica sub-layer [36].

Table 1. The depth of the MFON profile corrugation (average difference between	the upper
and lower points of the sample profile) for each deposited Ag thickness	

Ag thickness (nm)	44	110	135	200	620
Corrugation depth (nm)	220	110	170	180	110



Figure 4. Reflection spectra of the MFON substrates.

Figure 4 plots the reflection spectrum of each sample. The reflectivity for all samples is in the range 70-90 %. It is lower than for a planar Ag layer, as observed previously for Au MFONs [44]. This loss in specular reflectivity includes scattering effects by the corrugated surface as well as absorption by localized surface plasmon (LSP) modes. The spectra present a flat "plateau" profile above 500 nm similar to the reflection spectra of random gold patterns [51], which was attributed by the authors to localized surface plasmon (LSP) modes. The continuum of LSP frequencies in ref. 51 was explained and successfully modelled by the broad range of "hot spot" sizes and geometries present in the random fractal gold film [52]. The self-assembly fabrication process for MFONs thus seems to produce a diverse range of hot spot geometries leading to a continuum of LSP frequencies. This also offers a broad choice of excitation wavelengths for SERS experiments.

3.3. SERS study of the quantum dots

CdTeSe QDs and GQDs were deposited onto the Ag film surface.



Figure 5. Raman scattering spectra of the CdTeSe QDs on the MFON substrates with various Ag thicknesses, from 44 nm to 620 nm, and on a glass substrate. The excitation wavelength is 532 nm.

Figure 5 shows the Raman spectra of the CdTeSe QDs on different Ag thicknesses, compared to the Raman spectrum of these QDs residing on glass. The obtained spectra present a double line as usually seen in alloy QDs and characteristic of the two vibration lines of the CdTe-like LO phonon line and the CdSe-like LO phonon line residing respectively at 159 cm⁻¹ and 192 cm⁻¹. These Raman spectral lines are in complete agreement with the published vibration lines of CdTeSe [1, 53, 54]. The positions of these two Raman spectral lines are unchanged compared to QDs on glass, but their intensity is much higher for the MFON samples.



Figure 6. Raman scattering spectra of GQDs on MFON substrates with Ag thicknesses from 44 nm to 620 nm, and on a glass substrate. The excitation wavelength is 532 nm.

We also used our MFON substrates to analyze graphene quantum dots. Raman spectroscopy is the most familiar tool to identify the formation of GQDs. Fig. 6 shows the Raman spectra of GQDs with various Ag film thicknesses, along with the Raman spectrum of these GQDs on glass. Two peaks are observed at 1361 and 1575 cm⁻¹ (and their second-order replicas appear between 2500 and 3000 cm⁻¹). The peak at 1575 cm⁻¹ is assigned to the G peak, as observed in [16]. It corresponds to a first-order scattering process in graphene stemming from the doubledegenerate vibrational mode (E_{2g}) at the crossing of the longitudinal optical (LO) and transverse optical (TO) phonon bands at the Γ point in the first Brillouin zone [55, 56]. The peak at 1361 cm⁻¹ is assigned to the D peak [56]. The D peak of the Raman spectrum comes from the "unorganized" carbon [56, 57] which is associated with the defects or the edges of graphene. Both lines are strongly enhanced compared to the glass substrate.

There is thus a clear SERS effect for all MFON samples and for the two types of QDs. In order to quantify the improvement due to SERS, the SERS enhancement factor can be defined as the ratio between the Raman intensity per emitter on the substrate and the Raman intensity per emitter on the reference sample [20]. It must be noted that this standard definition of the SERS enhancement factor considers only the SERS intensity which is collected by the microscope objective and not the total SERS intensity. On a gold substrate, some light is reflected by the surface into the objective so that the collection efficiency can typically be expected to be better than on a glass substrate [58]. The measured enhancement factor thus reflects the cumulated effects of the enhanced excitation field, the enhanced emission and the modified collection efficiency.

The number of emitters contributing to the SERS signal is usually estimated with some uncertainty and the homogeneity of the emitters deposition should be checked [20]. Here, we estimate the droplet deposition surface to be approximately the same (4 mm diameter) for all samples. The excitation laser spot is kept constant (around 1 μ m size) as well as the concentration of the CdTeSe and GQD solutions. We checked that the emitters distribution was uniform by measuring (fig. 7) the Raman spectrum on different locations of the sample for the CdTeSe (left) and graphene (right) QDs. The spectra over the deposited surface were approximately the same with identical emission lines and 5 to 10% differences in intensities for all samples, demonstrating the good uniform distribution on the sample, however with more dense deposition on the sides of the droplet. Eventually, the number of emitters involved in the Raman signal is assumed to be the same for all samples so that the enhancement factor is obtained as the ratio between the Raman intensity of the sample and the reference.



Figure 7. Raman scattering spectra of CdTeSe QDs (left) and GQDs (right) at different positions on the 135-nm-Ag MFON sample. The excitation wavelength is 532 nm.

The obtained enhancement factors are listed in table 2. They range from 23 to 84 for the CdTeSe QDs and from 2 to 40 for the GQDs. It is remarkable that the maximal enhancement factor is obtained with the 135-nm-Ag sample for both types of QDs, while the 44-nm and 200-nm samples give minimal enhancement factors for both types of QDs. This appears as a sign that the different measured enhancement factors actually reveal plasmonic properties of the MFON samples, in spite of some uncertainty on the number of emitters, which can be common in SERS measurements as discussed in [20], and could appear here due to some deposition inhomogeneities.

The differences in enhancement factors between the CdTeSe and graphene QDs may be explained by different photophysical properties as well as by the emitters occupying different positions on the MFON surface with respect to the hot spots, depending on their sizes, ligands.... The measured enhancement factors are much smaller than the typical 10^8 ones reported for dye molecules on MFON substrates [20]. However, it should be noted that most of the few SERS studies on QDs did not report enhancement factor values. Only two publications reported enhancement factors of 40 to 700 for CdS QDs with Ag clusters [27] and 2000 for CdSe QDs with lithographic Au disks [30], both SERS studies being performed at excitation resonant with the plasmonic modes. Maximum values were obtained at 10^4 by tip-enhanced Raman scattering (TERS) [30] and 5.10^4 enhancement with respect to a flat gold film for an emitter in a thin nano-gap between two gold surfaces [34]. There is thus a general tendency for lower SERS enhancement factors with QDs than with dye molecules, and our measurements show that the same substrate can lead to different enhancement factors depending on which type of QD is considered.

MFON substrate Ag thickness (nm)	Raman intensity (a.u.)	CdTeSe QDs Enhancement factor	Raman intensity (a.u.)	Graphene QDs Enhancement factor
Glass reference	72	-	600	-
44 nm	2025	28	1116	2
110 nm	2591	36	2616	4
135 nm	6027	84	24004	40
200 nm	1628	23	1147	2
620 nm	3037	42	4837	8

Table 2. Enhancement factor values of QDs Raman intensity for samples with different Ag film thicknesses

The nano-gaps at the junction between spheres are known to constitute hot spots which play an important role on SERS properties in these substrates [37]. Numerical simulations show that the electromagnetic field can be confined in these nano-gaps over distances of a few tens of nanometers [37, 38, 40]. The enhancement factor is thus expected to be related in particular to the corrugation profile and to be decreased when the profile is smoothed. However, the 44-nm Ag film has the highest corrugation depth but its enhancement factor is not the highest one. Refs [37] and [38] considered SERS of dye molecules on MFONs for different Ag thicknesses (but with smaller silica spheres: respectively 430 and 350 nm diameter). Both found an optimal Ag thickness for SERS, respectively at 40 and 150 nm. The surface characteristics and the deposition conditions are probably important parameters which explain the different optimal thicknesses between the three experiments, ours and those of refs [37, 38]. The nanogap width is also a key parameter: it is generally smaller in ref. [37] than in [38], possibly explaining the higher enhancement factor in the former results. Ref. [39], on the other hand, used a 120-nm Ag layer and found that 1000-nm spheres provided the highest enhancement factor. The numerical simulations for these different reports yield quite different orders of magnitude for Ag MFON enhancement factors: ref. [37] estimates it from 3×10^5 to 1.5×10^6 , while ref. [39] computes a maximum enhancement of 6000 (and ref. [40] finds 6 x 10⁴ for Au MFONs). Some differences may be explained by the different metals (Au or Ag), thicknesses, sphere diameters and excitation wavelengths considered in the simulations. However the precise size and shape of the nano-gaps is probably also a key parameter (as demonstrated in ref. [37]) and is not easily probed experimentally. A clear general trend is that the orders of magnitude of the simulated enhancement factors are comparable with the measured ones for dye molecules [37] but much larger than the measured enhancements for QDs. These different results call for further studies on the different plasmonic coupling mechanisms for such samples. It has been shown that 25 % of the enhancement factors originates from the 0.01 % of molecules which are at the most confined plasmonic hot spots [59]. Nevertheless localized surface plasmons are also known to couple to surface-plasmon-polaritons (SPP) modes propagating over the Ag surface [60] and SPPs are known to contribute to photoluminescence enhancement on MFON samples [44]. While the MFON SERS has been attributed to the plasmonic resonances and nanogaps between the spheres [37, 39], photo-emission electron microscopy (PEEM) has also shown the importance of hot spots at defects of the MFON surface [60].

4. Conclusions

We have fabricated 600 nm SiO₂ spheres which were used for the fabrication of opal crystals. By adding an Ag metal layer, a metallic-film-on-nanospheres (MFON) surface with 2D periodic corrugation structure was fabricated in order to create a plasmonic surface with hot spots enhancing the electromagnetic field. Raman spectroscopy studies on both CdTeSe QDs and GQDs deposited on MFONs was performed. Enhancement of SERS was observed for all samples and for both QDs, with maximum effect for the 135 nm Ag film. The Raman spectra intensity was then enhanced by ~84 times compared to when measured on glass substrate for CdTeSe QDs and ~ 40 times for GQDs.

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